



# **Unidirectional Low Capacitance TVSarray**

#### **DESCRIPTION**

This USB50803 - USB50824 family of Transient Voltage Suppressor (TVS) arrays is packaged in an SO-8 configuration giving protection to 2 unidirectional data or interface lines. It is designed for use in applications where very low capacitance protection is required at the board level from voltage transients caused by electrostatic discharge (ESD) as defined in IEC 61000-4-2, electrical fast transients (EFT) per IEC 61000-4-4 and secondary effects of lightning. Using the schematic on the last page, pins 7 & 8 are tied together for the first protected positive line, and pins 1 & 2 are tied together to the ground. The same would then occur where pins 5 & 6 are tied together for a second protected positive line and pins 2 & 3 are tied together to the ground. If protecting a negative line with respect to ground, these may be switched in polarity connections where the pins are tied together in this manner for unidirectional protection.

These TVS arrays have a peak power rating of 500 watts for an 8/20 µsec pulse. This array is suitable for protection of sensitive circuitry such as TTL, CMOS DRAM's, SRAM's, HCMOS, HSIC microprocessors, Universal Serial Bus (USB) and I/O transceivers.



Important: For the latest information, visit our website <a href="http://www.microsemi.com">http://www.microsemi.com</a>.

#### **FEATURES**

- Provides electrically isolated protection for up to 2 unidirectional lines.
- Surge protection per IEC 61000-4-2 and IEC 61000-4-4.
- UL 94V-0 flammability classification.
- Ultra low capacitance; 3 pF per line pair.
- Ultra low leakage current.
- RoHS compliant versions available.

#### **APPLICATIONS / BENEFITS**

EIA-RS485 data rates: 5 Mbs

10 Base T Ethernet. USB data rate: 900 Mbs

# **MAXIMUM RATINGS**

Parameters/Test Conditions	Symbol	Value	Unit
Junction and Storage Temperature	$T_J$ and $T_{STG}$	-55 to +150	°C
Peak Pulse Power @ 8/20 μs (see figure 1)	P <sub>PP</sub>	500	W
Impulse Repetition Rate	df	< .01	%
Capacitance (f = 1 MHz) @ 0 V	С	3	pF
Solder Temperature @ 10 s	T <sub>SP</sub>	260	°C



# SO-8 Package

# Also available:

## **Bidirectional version** (with opposite polarity in

each leg) USB50803C(-A) -USB50824C(-A)

### MSC - Lawrence

6 Lake Street. Lawrence, MA 01841 Tel: 1-800-446-1158 or (978) 620-2600 Fax: (978) 689-0803

#### MSC - Ireland

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

#### Website:

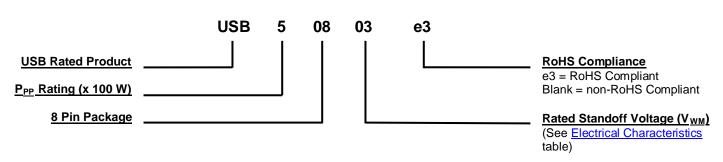
www.microsemi.com



## **MECHANICAL and PACKAGING**

- CASE: Molded SO-8 surface mount.
- TERMINALS: Tin-lead or RoHS compliant annealed matte-tin plating.
- MARKING: Logo, device marking code (see electrical characteristics table), date code.
- POLARITY: Pin #1 marked by dot on top of package.
- TAPE & REEL option: Per EIA standard 481. Consult factory for quantities. Carrier tubes with a quantity of 95 pieces are standard.
- WEIGHT: 0.066 grams (approximate).
- See <u>Package Dimensions</u> on last page.

# PART NOMENCLATURE



SYMBOLS & DEFINITIONS				
Symbol	Definition			
V <sub>WM</sub>	Stand Off Voltage: Maximum dc voltage that can be applied over the operating temperature range.  V <sub>WM</sub> must be selected to be equal or be greater than the operating voltage of the line to be protected.			
$V_{(BR)}$	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.			
Vc	Clamping Voltage: Maximum clamping voltage across the TVS device when subjected to a given current at a pulse time of 20 $\mu$ s.			
I <sub>D</sub>	Standby Current: Leakage current at V <sub>WM</sub> .			
С	Capacitance: Capacitance of the TVS as defined @ 0 volts at a frequency of 1 MHz and stated in picofarads.			

#### **ELECTRICAL CHARACTERISTICS**

PART NUMBER	DEVICE MARKING*	STAND- OFF VOLTAGE V <sub>WM</sub> Volts	BREAKDOWN VOLTAGE V <sub>(BR)</sub> @1 mA Volts MIN	CLAMPING VOLTAGE Vc @ 1 Amp (Figure 2) Volts MAX	CLAMPING VOLTAGE Vc @ 5 Amp (Figure 2) Volts MAX	STANDBY CURRENT I <sub>D</sub> @ V <sub>WM</sub> µA	CAPACITANCE (f = 1 MHz) C @ 0 V pF MAX	TEMPERATURE COEFFICIENT OF V <sub>(BR)</sub> α <sub>VBR</sub> mV/°C MAX
USB50803	AF	3.3	4	8	11	200	3	-5
USB50805	AG	5.0	6.0	10.8	13	20	3	1
USB50812	AH	12.0	13.3	19	26	1	3	8
USB50815	AJ	15.0	16.7	24	32	1	3	11
USB50824	AK	24.0	26.7	43	57	1	3	28

<sup>\*</sup> Device marking has an e3 suffix added for the RoHS compliant option, e.g. AFe3, AGe3, AHe3, AJe3, and AKe3.

**NOTE:** Transient Voltage Suppressor (TVS) products are normally selected based on their standoff voltage Vwm. The selected voltage should be equal to or greater than the peak operating voltage of the circuit to be protected.



## **GRAPHS**

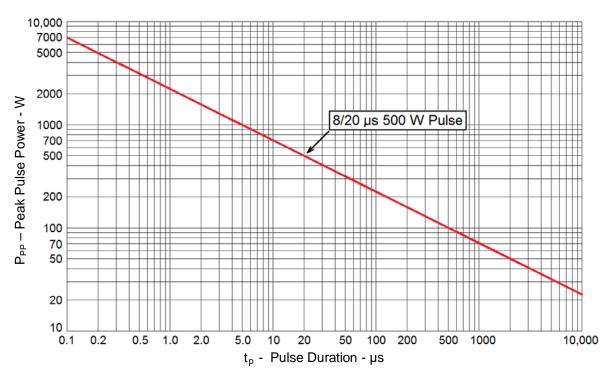


FIGURE 1
Peak Pulse Power vs Pulse Time

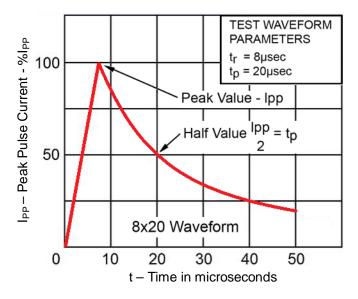
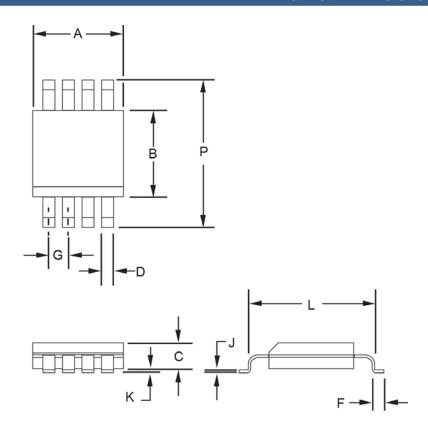


FIGURE 2
Pulse Waveform



# PACKAGE DIMENSIONS



	Dimensions					
Ltr	Ind	ch	Millimeters			
	Min	Max	Min	Max		
Α	0.188	0.197	4.77	5.00		
В	0.150	0.158	3.81	4.01		
С	0.053	0.069	1.35	1.75		
D	0.011	0.021	0.28	0.53		
F	0.0160	0.050	0.041	1.27		
G	0.050 BSC		1.27 BSC			
J	0.006	0.010	0.15	0.25		
K	0.004	0.008	0.10	0.20		
L	0.189	0.206	4.80	5.23		
Р	0.228	0.244	5.79	6.19		

# PAD LAYOUT / SCHEMATIC

